



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



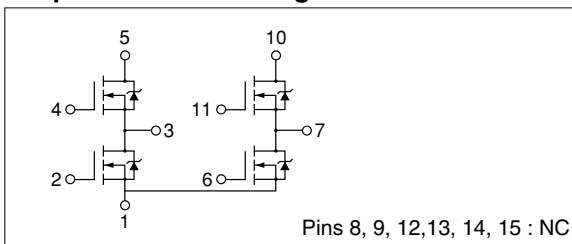
Absolute maximum ratings

($T_a=25^\circ\text{C}$)

Symbol	Ratings	Unit
V_{DSS}	60	V
V_{GSS}	± 20	V
I_D	7	A
$I_D(\text{pulse})$	15 ($PW \leq 100\mu\text{s}$, $D_u \leq 1\%$)	A
E_{AS}^*	60	mJ
I_{AS}	7	A
P_T	4.8 ($T_a=25^\circ\text{C}$, with all circuits operating, without heatsink)	W
	35 ($T_c=25^\circ\text{C}$, with all circuits operating, with infinite heatsink)	
θ_{j-a}	26 (Junction-Air, $T_a=25^\circ\text{C}$, with all circuits operating)	$^\circ\text{C/W}$
θ_{j-c}	3.57 (Junction-Case, $T_c=25^\circ\text{C}$, with all circuits operating)	$^\circ\text{C/W}$
V_{ISO}	1000 (Between fin and lead pin, AC)	V _{rms}
T_{ch}	150	$^\circ\text{C}$
T_{stg}	-40 to +150	$^\circ\text{C}$

* : $V_{DD}=20\text{V}$, $L=20\text{mH}$, $I_D=2\text{A}$, unclamped, $R_G=50\Omega$, see Fig. E on page 15.

Equivalent circuit diagram



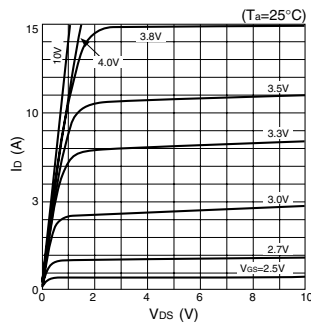
Electrical characteristics

($T_a=25^\circ\text{C}$)

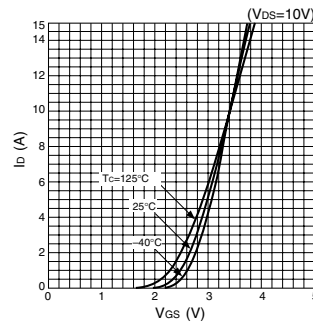
Symbol	Specification			Unit	Conditions
	min	typ	max		
$V_{(BR)DSS}$	60			V	$I_D=100\mu\text{A}$, $V_{GS}=0\text{V}$
I_{GSS}			± 100	nA	$V_{GS}=\pm 20\text{V}$
I_{DSS}			100	μA	$V_{DS}=60\text{V}$, $V_{GS}=0\text{V}$
V_{TH}	1.0		2.0	V	$V_{DS}=10\text{V}$, $I_D=250\mu\text{A}$
$R_{e(yfs)}$	6			S	$V_{DS}=10\text{V}$, $I_D=3.5\text{A}$
$R_{DS(ON)}$			0.1	Ω	$V_{GS}=10\text{V}$, $I_D=3.5\text{A}$
C_{iss}		660		pF	$V_{DS}=10\text{V}$, $f=1.0\text{MHz}$, $V_{GS}=0\text{V}$
C_{oss}		310		pF	
C_{rss}		75		pF	
$t_{d(on)}$		30		ns	$I_D=3.5\text{A}$, $V_{DD} \approx 20\text{V}$, $R_L=5.7\Omega$, $V_{GS}=5\text{V}$, see Fig. 3 on page 16.
t_r		90		ns	
$t_{d(off)}$		140		ns	
t_f		65		ns	
V_{SD}		1.1		V	
t_{rr}		80		ns	$I_{SD}=3.5\text{A}$, $di/dt=100\text{A}/\mu\text{s}$

Characteristic curves

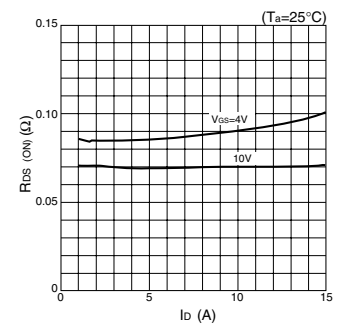
I_D - V_{DS} Characteristics (Typical)



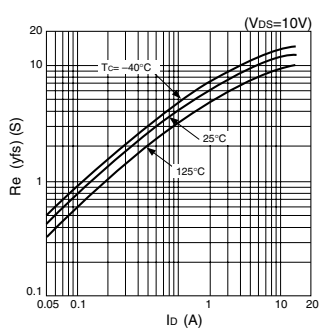
I_D - V_{GS} Characteristics (Typical)



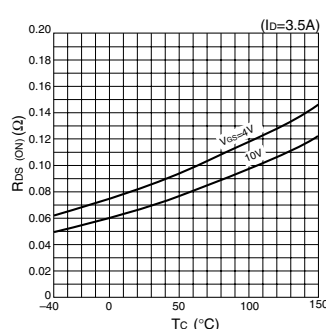
$R_{DS(ON)}$ - I_D Characteristics (Typical)



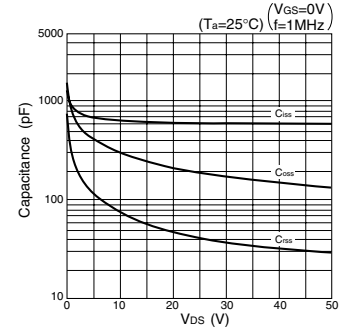
$R_{e(yfs)}$ - I_D Characteristics (Typical)



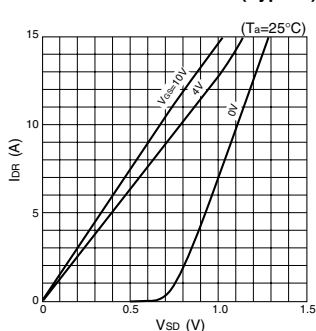
$R_{DS(ON)}$ - T_c Characteristics (Typical)



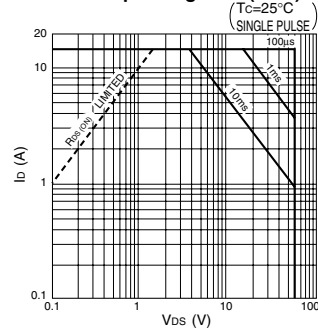
Capacitance- V_{DS} Characteristics (Typical)



I_{DR} - V_{SD} Characteristics (Typical)



Safe Operating Area (SOA)



P_T - T_a Characteristics

